# TPS715 50mA、24V、3.2μA 静态电流、低压降线性稳压器

## 1 特性

- 输入电压范围：
  - 2.5V 至 24V（仅新芯片最大电压为 30V）
- 可配置的输出电压选项：
  - 固定：1.8V 至 5V
  - 可调节：1.205 V 至 15 V
- 输出电流：高达 50 mA
- 超低 $I_Q$：50mA 负载电流下为 3.2μA
- 与 ≥ 0.47μF 的输出电容器一起工作时可保持稳定
- 过流保护
- 封装：5 引脚 SC70 (DCK)
- 工作结温：–40°C 至 +125°C
- 有关 80mA 额定电流和更高功率的封装，请参阅 TPS715A

## 2 应用

- 家庭和楼宇自动化
- 零售自动化和支付
- 电网基础设施
- 医疗应用
- 照明应用

## 3 说明

TPS715 低压降 (LDO) 线性稳压器是低静态电流器件，可提供采用微型封装、具有宽输入电压范围和实现低功耗运行的优势。因此，TPS715 专为电池供电型应用而设计，可用作低功耗微控制器的电源管理附件。

TPS715 有固定电压和可调节电压两种版本可供选用。为了获得更大的灵活性或更高的输出电压，可调节电压版本使用反馈电阻器将输出电压设置为 1.205V 至 15V。TPS715 LDO 在负载电流为 50mA 时支持典型值为 415mV 的低压降。低静态电流（典型值为 3.2μA）在整个输出负载电流（0mA 至 50mA）范围内都是稳定的。TPS715 还具有内部软启动功能，可降低浪涌电流。内置过流限制有助于在发生负载短路或故障时保护稳压器。

**封装信息**(1)

| 器件型号 | 封装 | 封装尺寸（标称值） |
|---|---|---|
| TPS715 | DCK（SC70，5） | 2.00mm × 1.25mm |

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

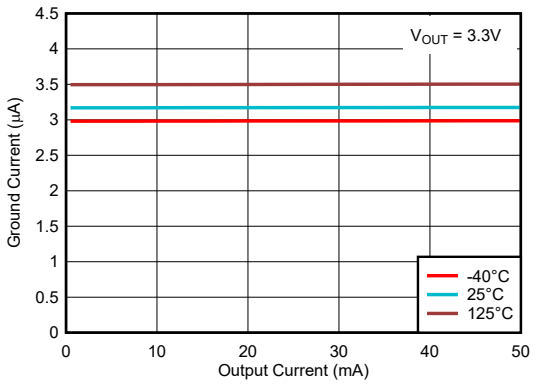
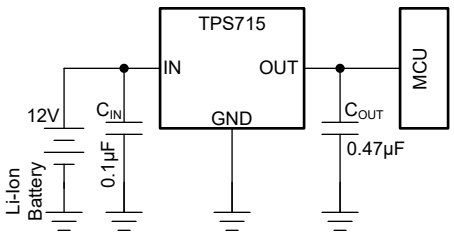



图 3-1. TPS715xx 的静态电流与负载电流（仅限新芯片）




典型应用原理图

本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前，请务必参考最新版本的英文版本。

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## 4 Revision History

注：以前版本的页码可能与当前版本的页码不同

**Changes from Revision S (August 2022) to Revision T (December 2022)** **Page**

- 向文档中添加了 M3 器件的信息（新芯片信息） ... 1
- 更改了*特性* 部分：更改了可调输出电压选项，将*额定结温* 更改为*工作结温*，并重新排列了*特性* 要点 ... 1
- 向首页添加了*静态电流与负载电流* 曲线 ... 1
- 删除了*说明* 部分中的低功率级别讨论 ... 1
- 更改了*典型应用原理图* ... 1
- Changed *Pin Functions* table: changed *Description* column and added footnote ... 4
- Added condition statement and characterization conditions plots to *Typical Characteristics* section ... 8
- Changed curve titles in *Typical Characteristics* section to distinguish between new and legacy chips ... 8
- Changed block diagrams in *Functional Block Diagrams* section ... 11
- Changed *Low Quiescent Current* section and title ... 12
- Deleted thermal shutdown discussion from *Current Limit* section ... 12
- Changed third bullet in *Normal Operation* section ... 14
- Changed *Application Information* section ... 15
- Changed *Typical Application* section ... 15
- Changed output operating voltage range from *1.2 V to 15 V* to *1.205 V to 15 V* in *Setting VOUT for the TPS71501 Adjustable LDO* ... 15
- Added reverse current limit discussion to *Reverse Current* section ... 16
- Changed *Application Curves* section ... 19
- Deleted sentence stating *This input supply must be well regulated* from *Power Supply Recommendations* section ... 20
- Changed *Example Layout for the TPS71501DCK* figure ... 21
- Changed *Device Nomenclature* table ... 22


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**Changes from Revision R (February 2015) to Revision S (August 2022)** **Page**

- 更新了整个文档中的表格、图和交叉参考的编号格式 ..... 1
- 更改了文档标题 ..... 1
- 更改了*特性* 部分 ..... 1
- 更改了*应用* 部分 ..... 1
- 更改了*说明* 部分 ..... 1
- Changed descriptions of FB and NC pins in *Pin Functions* table, split fixed and adjustable pin outs apart ..... 4
- Added new chip specific plots to *Typical Characteristics* section ..... 8
- Changed *Overview* section ..... 11
- Changed block diagrams in *Functional Block Diagrams* section ..... 11
- Changed *Low Quiescent Current* section and title ..... 12
- Changed *Dropout Voltage* ($V_{DO}$) section ..... 12
- Deleted *Disabled* row from *Device Functional Mode Comparison* table ..... 14
- Changed *Dropout Operation* section ..... 14
- Changed *External Capacitor Requirements* section ..... 16
- Added *Input and Output Capacitor Requirements* section ..... 16
- Changed *Reverse Current* section ..... 16
- Changed output voltage value when no $C_{FF}$ is used from *0.8 V* to *1.205 V* ..... 17
- Added *Power Dissipation* ($P_D$) section ..... 17
- Added new chip specific plots to *Application Curves* section ..... 19
- Added second row and deleted second footnote from *Device Nomenclature* table ..... 22

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## 5 Pin Configuration and Functions

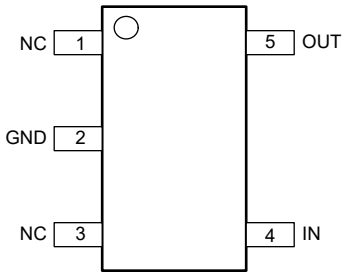


图 5-1. DCK Package (Fixed), 5-Pin SC70 (Top View)

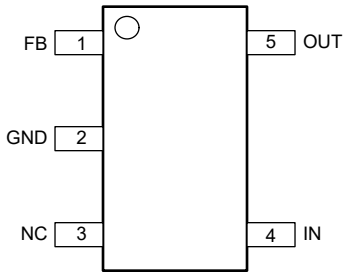


图 5-2. DCK Package (Adjustable), 5-Pin SC70 (Top View)

表 5-1. Pin Functions

| PIN | | | TYPE | DESCRIPTION |
|---|---|---|---|---|
| NAME | FIXED | ADJUSTABLE | | |
| FB | — | 1 | I | In the adjustable configuration, this pin sets the output voltage with the help of the feedback divider. |
| GND | 2 | 2 | — | Ground pin. |
| IN | 4 | 4 | I | Input supply pin. A capacitor with a value of 0.1 µF or larger is recommended from this pin to ground. See the *Input and Output Capacitor Requirements* section for more information. |
| NC | 1, 3 | 3 | — | No connect pin. This pin is not connected internally. Connect this pin to ground for best thermal performance or leave floating. |
| OUT | 5 | 5 | O | Output of the regulator. A capacitor with a value of 1 µF or larger is required from this pin to ground.(1) See the *Input and Output Capacitor Requirements* section for more information. |

(1) The nominal output capacitance must be greater than 0.47 µF. Throughout this document, the nominal derating on these capacitors is 50%. Make sure that the effective capacitance at the pin is greater than 0.47 µF.


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# 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)[1] [2]

| | | MIN | MAX | UNIT |
|---|---|---|---|---|
| Voltage | $V_{IN}$ (for legacy chip only) | – 0.3 | 24 | V |
| | $V_{IN}$ (for new chip only) | – 0.3 | 30 | |
| | $V_{OUT}$ (for legacy chip only) | – 0.3 | 16.5 | |
| | $V_{OUT}$ (for fixed output new chip only) | – 0.3 | 2 X $V_{OUT(typ)}$ or $V_{IN}$ + 0.3V or 5.5V (whichever is lower) | |
| Voltage | $V_{OUT}$ (for adjustable output new chip only) | – 0.3 | $V_{IN}$ + 0.3 | V |
| | $V_{FB}$ (for adjustable output new chip only) | | 2.4 | |
| | $V_{FB}$ (for adjustable output legacy chip only) | – 0.3 | 4.5 | |
| Current | Peak output current | Internally limited | | |
| Temperature | Junction, $T_J$ | – 40 | 150 | °C |
| | Storage, $T_{stg}$ | – 65 | 150 | |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values are with respect to network ground terminal.

## 6.2 ESD Ratings

| | | | VALUE | UNIT |
|---|---|---|---|---|
| $V_{(ESD)}$ | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1] | ±2000 | V |
| | | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins[2] | ±500 | |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)[1]

| | | MIN | NOM | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{IN}$ | Input supply voltage | 2.5 | | 24 | V |
| $V_{OUT}$ | Output voltage | 1.205 | | 15 | |
| $I_{OUT}$ | Output current | 0 | | 50 | mA |
| $C_{IN}$ | Input capacitor[2] | 0 | 0.047 | | µF |
| $C_{OUT}$ | Output capacitor (for legacy chip only) | 0.47 | 1 | | |
| | Output capacitor (for new chip only) [3] | 1 | | | |
| $T_J$ | Operating junction temperature | -40 | | 125 | °C |

(1) All voltages are with respect to GND.
(2) An input capacitor is not required for LDO stability. However, an input capacitor with an effective value of 0.047 µF is recommended to counteract the effect of source resistance and inductance, which may in some cases cause symptoms of system level instability such as ringing or oscillation, especially in the presence of load transients.
(3) All capacitor values are assumed to derate to 50% of the nominal capacitor value. Maintain an effective output capacitance of 0.47 µF minimum for the stability.

## Thermal Information

| THERMAL METRIC [1] | | Legacy Chip DCK (SC-70) 5 PINS | New Chip DCK (SC-70) 5 PINS | UNIT |
|---|---|---|---|---|
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 253.8 | 195.7 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 73.7 | 88.2 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 84.6 | 40.7 | °C/W |
| $\psi_{JT}$ | Junction-to-top characterization parameter | 1.1 | 11.2 | °C/W |
| $\psi_{JB}$ | Junction-to-board characterization parameter | 83.9 | 40.5 | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.


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## 6.4 Electrical Characteristics

over operating junction temperature range ($T_J$ = –40°C to 125°C), $V_{IN}$ = $V_{OUT(nom)}$ + 1 V, $I_{OUT}$ = 1 mA, and $C_{OUT}$ = 1 µF (unless otherwise noted); typical values are at $T_J$ = 25°C

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| $V_{IN}$ | Input voltage (1) | $I_O$ = 10 mA | 2.5 | | 24 | V |
| | | $I_O$ = 50 mA | 3 | | 24 | |
| $V_{OUT}$ | Output voltage range (TPS71501) | | 1.205 | | 15 | V |
| | Output voltage accuracy (1) (2) | $V_{OUT}$ + 1 V ≤ $V_{IN}$ ≤ 24 V, 100 µA ≤ $I_{OUT}$ ≤ 50 mA | –4 | | 4 | % |
| $I_{GND}$ | Ground pin current (legacy chip)(3) | 0 ≤ $I_{OUT}$ ≤ 50 mA , $T_J$ = –40°C to 85°C | | 3.2 | 4.2 | µA |
| | | 0 mA ≤ $I_{OUT}$ ≤ 50 mA | | 3.2 | 4.8 | |
| | | 0 mA ≤ $I_{OUT}$ ≤ 50 mA , $V_{IN}$ = 24 V | | | 5.8 | |
| | Ground pin current (new chip) (3) | 0 ≤ $I_{OUT}$ ≤ 50 mA , $T_J$ = –40°C to 85°C | | 3.2 | 4.1 | |
| | | 0 mA ≤ $I_{OUT}$ ≤ 50 mA | | 3.2 | 4.3 | |
| | | 0 mA ≤ $I_{OUT}$ ≤ 50 mA , $V_{IN}$ = 24 V | | | 4.5 | |
| $\Delta V_{OUT}$ ($\Delta$IOUT) | Load regulation | $I_{OUT}$ = 100 µA to 50 mA | | 22 | | mV |
| $\Delta V_{OUT}$ ($\Delta$VIN) | Output voltage line regulation (legacy chip) (1) | $V_{OUT(NOM)}$ + 1 V ≤ $V_{IN}$ ≤ 24 V | | 20 | 60 | mV |
| | Output voltage line regulation (new chip) (1) | $V_{OUT(NOM)}$ + 1 V ≤ $V_{IN}$ ≤ 24 V | | 20 | 22 | |
| $V_n$ | Output noise voltage (legacy chip) (4) | BW = 200 Hz to 100 kHz, $C_{OUT}$ = 10 µF, $I_{OUT}$ = 50 mA | | 575 | | µVrms |
| | Output noise voltage (new chip)(4) | BW = 200 Hz to 100 kHz, $C_{OUT}$ = 10 µF, $I_{OUT}$ = 50 mA | | 425 | | |
| $I_{CL}$ | Output current limit (legacy chip) | $V_{OUT}$ = 0 V, $V_{IN}$ ≥ 3.5 V | 125 | | 750 | mA |
| | | $V_{OUT}$ = 0 V, $V_{IN}$ < 3.5 V | 90 | | 750 | |
| | Output current limit (new chip) | $V_{OUT}$ = 0 V, $V_{IN}$ ≥ 3.5 V | 125 | | 350 | |
| | | $V_{OUT}$ = 0 V, $V_{IN}$ < 3.5 V | 90 | | 350 | |
| PSRR | Power-supply ripple rejection | f = 100 kHz, $C_{OUT}$ = 10 µF | | 60 | | dB |
| $V_{DO}$ | Dropout voltage (legacy chip) | $I_{OUT}$ = 50 mA, $V_{IN}$ = $V_{OUT(nom)}$ – 0.1 V | | 415 | 750 | mV |
| | Dropout voltage (new chip) | | | 415 | 525 | |

(1) Minimum $V_{IN}$ = $V_{OUT}$ + $V_{DO}$ or the value shown for *Input voltage* in this table, whichever is greater.
(2) For adjustable device, output accuracy excludes the tolerance and mismatch associated with external resistors used for setting up the output voltage level.
(3) This device employs a leakage null control circuit. This circuit is active only if output current is less than pass FET leakage current. The circuit is typically active when output load is less than 5 µA, $V_{IN}$ is greater than 18 V, and die temperature is greater than 100°C.
(4) See Device Nomenclature for details about new and legacy chip descriptions

## 6.5 Typical Characteristics

at operating temperature $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 1.0 V or 2.5 V (whichever is greater), $I_{OUT}$ = 1mA, $C_{IN}$ = 1 µF, and $C_{OUT}$ = 1 µF (unless otherwise noted)

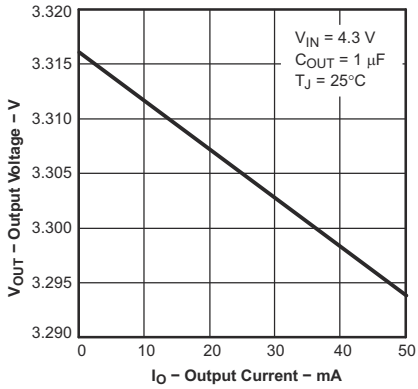


**图 6-1. Output Voltage vs Output Current for Legacy Chip**

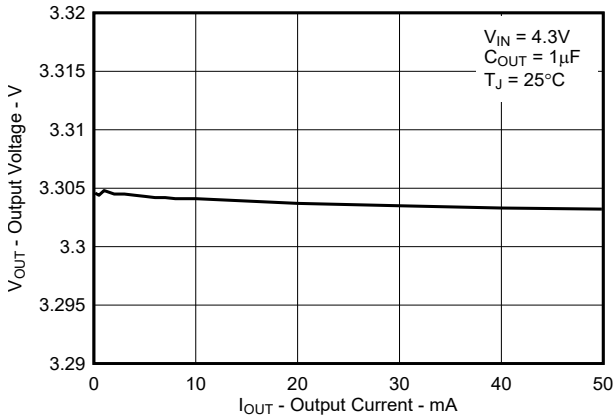


**图 6-2. Output Voltage vs Output Current for New Chip**

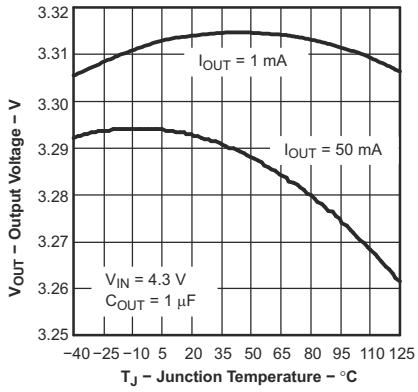


**图 6-3. Output Voltage vs Junction Temperature for Legacy Chip**

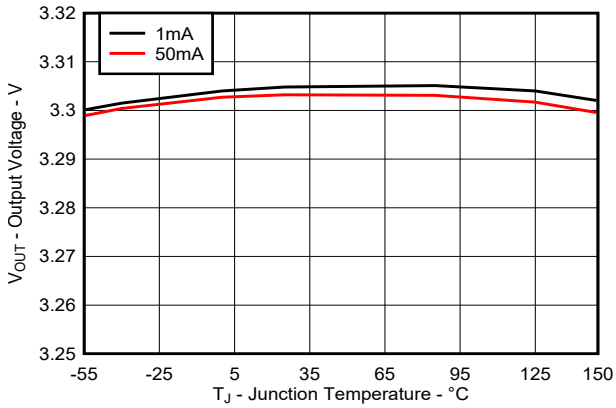


**图 6-4. Output Voltage vs Junction Temperature for New Chip**

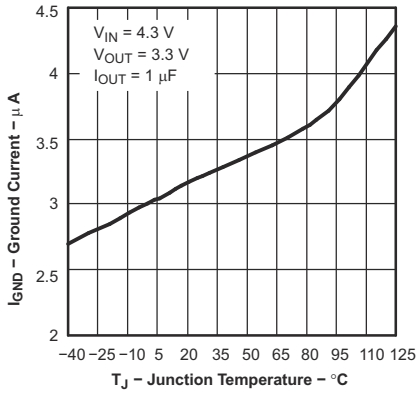


**图 6-5. Quiescent Current vs Junction Temperature for Legacy Chip**

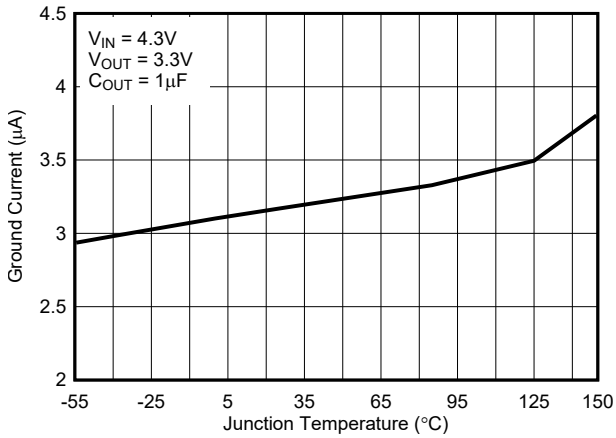


**图 6-6. Quiescent Current vs Junction Temperature for New Chip**


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## 6.5 Typical Characteristics (continued)

at operating temperature $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 1.0 V or 2.5 V (whichever is greater), $I_{OUT}$ = 1mA, $C_{IN}$ = 1 µF, and $C_{OUT}$ = 1 µF (unless otherwise noted)

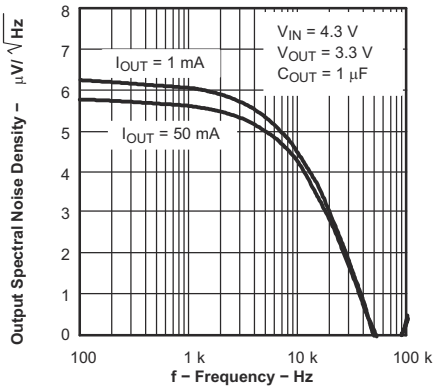
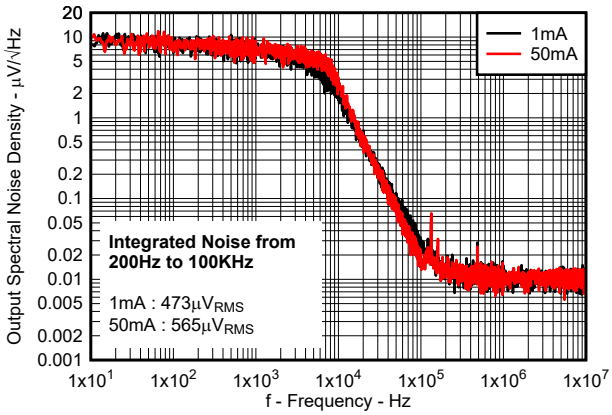



**图 6-7. Output Voltage Spectral Noise Density vs Frequency for Legacy Chip**




Integrated noise vs $I_{LOAD}$, $V_{IN}$ = 4.3V, $V_{OUT}$ = 3.3V ,

**图 6-8. Output Voltage Spectral Noise Density vs Frequency for New Chip**

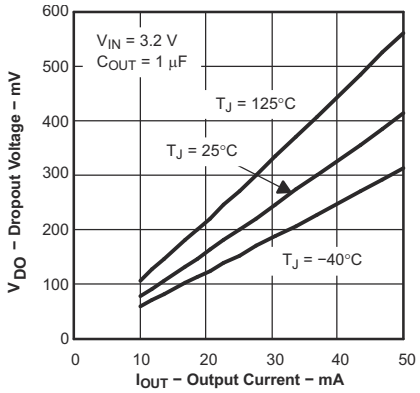



**图 6-9. Dropout Voltage vs Output Current for Legacy Chip**

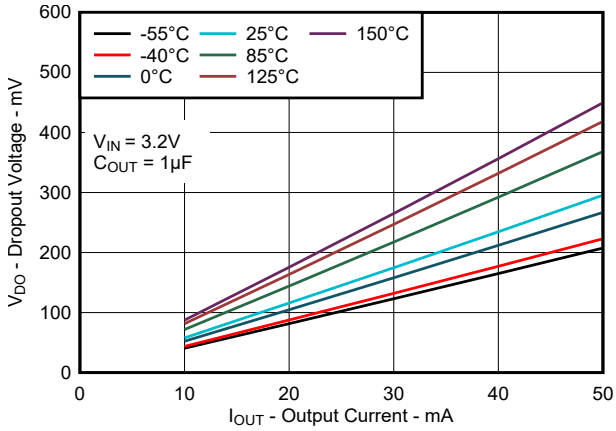



**图 6-10. Dropout Voltage vs Output Current for New Chip**

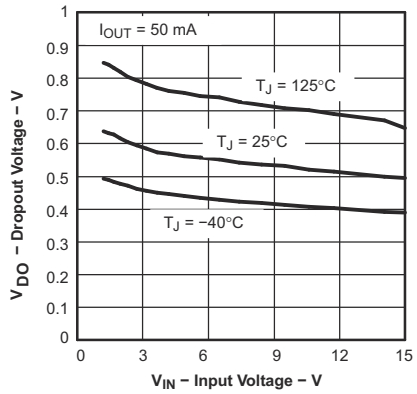



**图 6-11. TPS71501 Dropout Voltage vs Input Voltage for Legacy Chip**

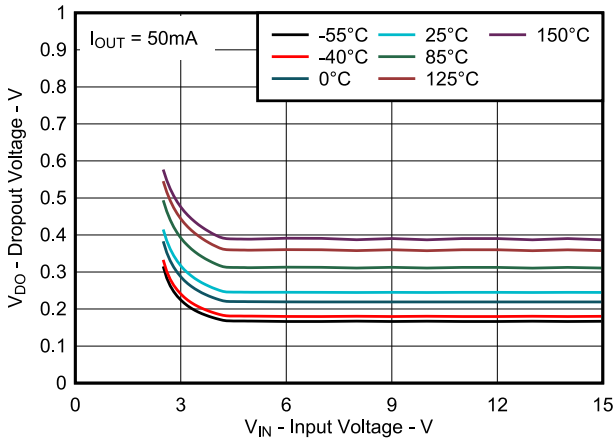



**图 6-12. TPS71501 Dropout Voltage vs Input Voltage for New Chip**

## 6.5 Typical Characteristics (continued)

at operating temperature $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 1.0 V or 2.5 V (whichever is greater), $I_{OUT}$ = 1mA, $C_{IN}$ = 1 µF, and $C_{OUT}$ = 1 µF (unless otherwise noted)

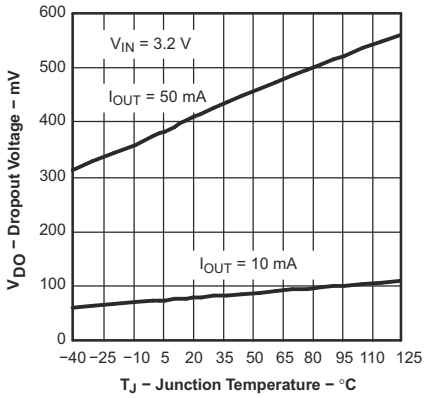



**图 6-13. Dropout Voltage vs Junction Temperature for Legacy Chip**

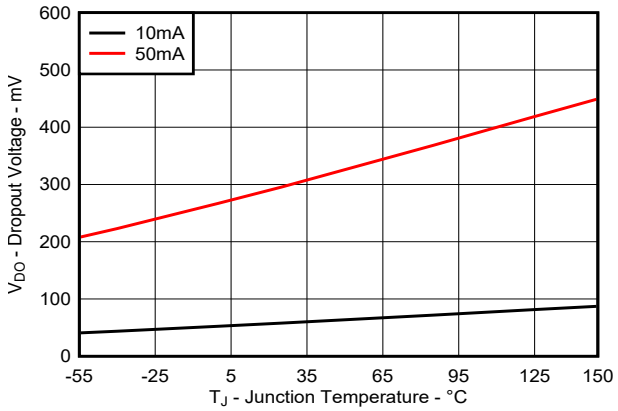



**图 6-14. Dropout Voltage vs Junction Temperature for New Chip**

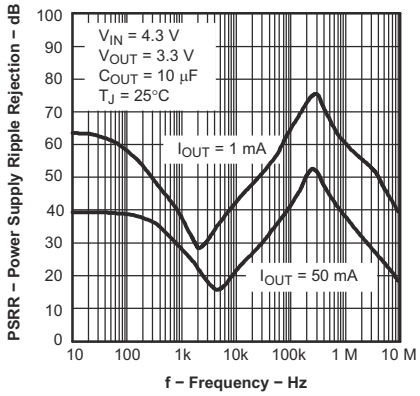



**图 6-15. Power-Supply Ripple Rejection vs Frequency for Legacy Chip**

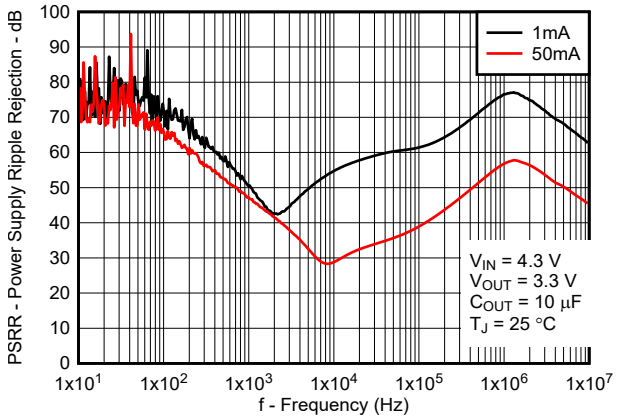



**图 6-16. Power-Supply Ripple Rejection vs Frequency for New Chip**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# 7 Detailed Description

## 7.1 Overview

The TPS715 low-dropout regulator (LDO) consumes only 3.2 μA (typ) of quiescent current across the entire output current range, while offering a wide input voltage range and low-dropout voltage in small packaging. The device, which operates over an input range of 2.5 V to 24 V, is stable with any output capacitor greater than or equal to 0.47 μF. The low quiescent current across the complete load current range makes the TPS715 optimal for powering battery-operated applications. The TPS715 has internal soft-start to control inrush current into the output capacitor. This LDO also has overcurrent protection during a load-short or fault condition on the output.

## 7.2 Functional Block Diagrams

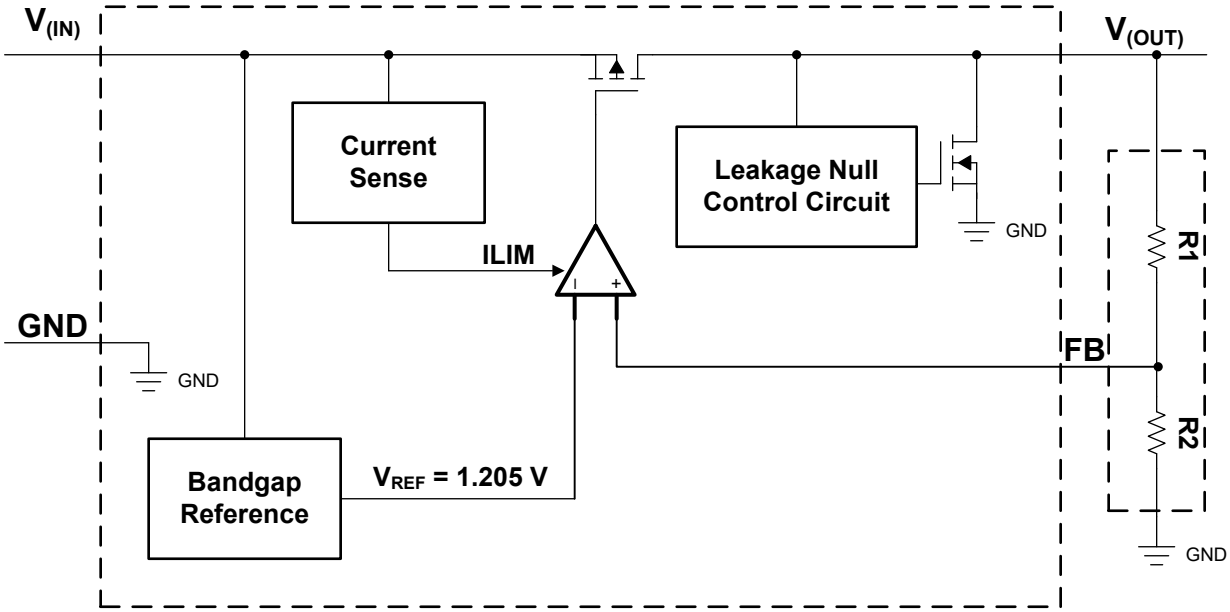


图 7-1. Functional Block Diagram—Adjustable Version

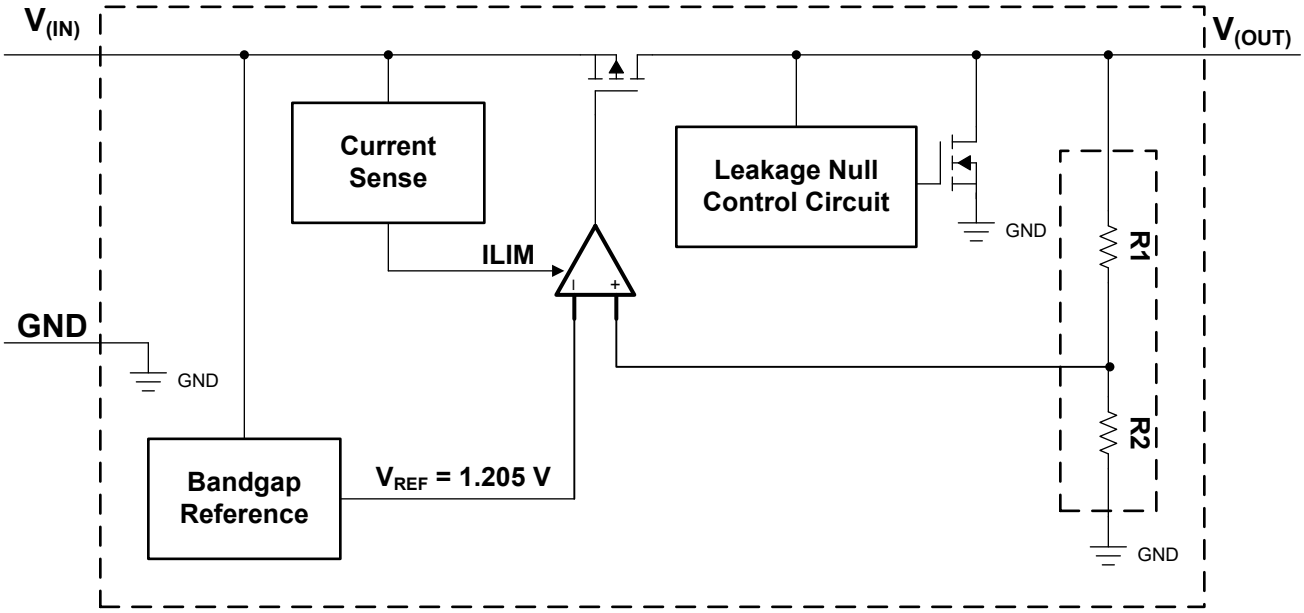


图 7-2. Functional Block Diagram—Fixed Version

## 7.3 Feature Description

### 7.3.1 Wide Supply Range

This device has an operational input supply range of 2.5 V to 24 V, allowing for a wide range of applications. This wide supply range is designed for applications that have either large transients or high DC voltage supplies.

### 7.3.2 Low Quiescent Current

This device only requires 3.2 μA (typical) of quiescent current across the complete load current range (0 mA to 50 mA) from –40°C to +125°C.

### 7.3.3 Dropout Voltage ($V_{DO}$)

Dropout voltage ($V_{DO}$) is defined as the input voltage minus the output voltage ($V_{IN}$ – $V_{OUT}$) at the rated output current ($I_{RATED}$), where the pass transistor is fully on. $I_{RATED}$ is the maximum $I_{OUT}$ listed in the *Recommended Operating Conditions* table. In dropout operation, the pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the value required to maintain output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source, on-state resistance ($R_{DS(ON)}$) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. Use 方程式 1 to calculate the $R_{DS(ON)}$ of the device.

$$R_{DS(ON)} = \frac{V_{DO}}{I_{RATED}} \tag{1}$$

### 7.3.4 Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a brick-wall scheme. In a high-load current fault, the brick-wall scheme limits the output current to the current limit ($I_{CL}$). $I_{CL}$ is listed in the *Electrical Characteristics* table.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brick-wall current limit, the pass transistor dissipates power [($V_{IN}$ – $V_{OUT}$) × $I_{CL}$]. For more information on current limits, see the *Know Your Limits* application note.

图 7-3 shows a diagram of the current limit.


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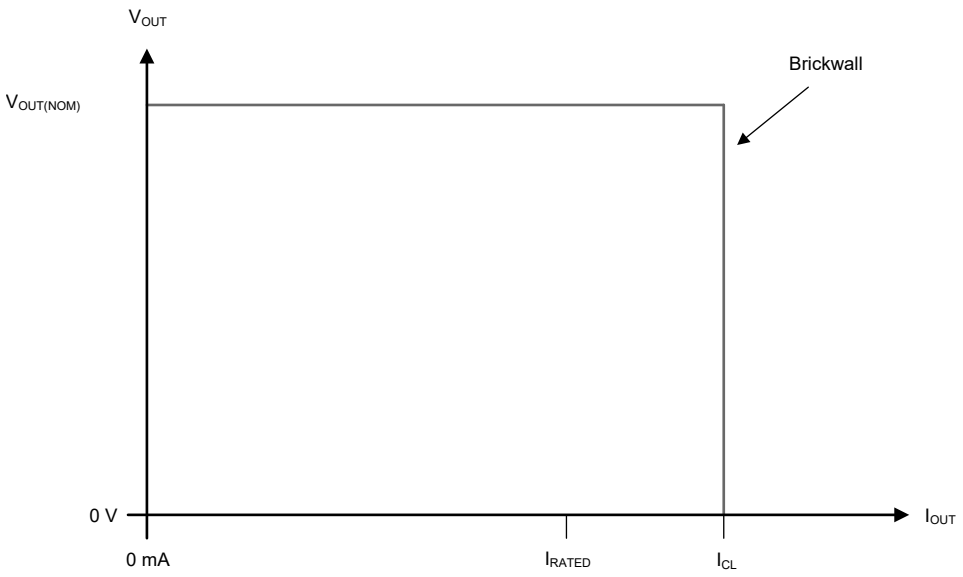


**图 7-3. Current Limit**

## 7.4 Device Functional Modes

表 7-1 provides a quick comparison between the normal, dropout, and disabled modes of operation.

**表 7-1. Device Functional Mode Comparison**

| OPERATING MODE | PARAMETER | |
|---|---|---|
| | $V_{IN}$ | $I_{OUT}$ |
| Normal | $V_{IN} > V_{OUT(nom)} + V_{DO}$ | $I_{OUT} < I_{CL}$ |
| Dropout | $V_{IN} < V_{OUT(nom)} + V_{DO}$ | $I_{OUT} < I_{CL}$ |

### 7.4.1 Normal Operation

The device regulates to the nominal output voltage under the following conditions:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_{OUT} < I_{CL}$)
- The device junction temperature is greater than –40°C and less than +125°C

### 7.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.


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# 8 Application and Implementation

**备注**

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

## 8.1 Application Information

The TPS715 family of LDO regulators is designed for battery-powered applications and is a good supply for low-power microcontrollers (such as the MSP430) because of the device family low $I_Q$ performance across load current range. The ultra-low-supply current of the TPS715 device maximizes efficiency at light loads, and the high input voltage range and flexibility of output voltage selection in the adjustable configuration and fixed output levels makes the device an optimal supply for building automation and power tools.

## 8.2 Typical Application

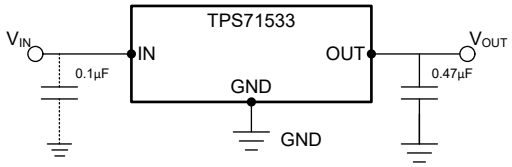
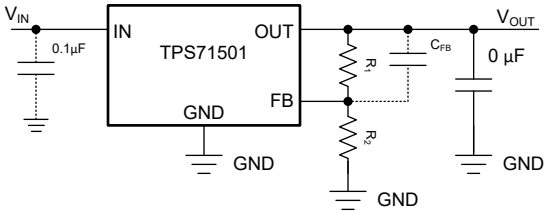



**图 8-1. Typical Application Circuit (Fixed-Voltage Version)**




| Output Voltage | R1 | R2 |
|---|---|---|
| 1.8V | 0.499 MΩ | 1MΩ |
| 2.8V | 1.33 MΩ | 1MΩ |
| 5.0V | 3.16 MΩ | 1MΩ |

**图 8-2. TPS71501 Adjustable LDO Regulator Programming**

### 8.2.1 Detailed Design Procedure

#### *8.2.1.1 Setting $V_{OUT}$ for the TPS71501 Adjustable LDO*

The TPS715 family contains an adjustable version, the TPS71501, which sets the output voltage using an external resistor divider as shown in 图 8-2. The output voltage operating range is 1.205 V to 15 V, and is calculated using:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right) \tag{2}$$

where:

- $V_{REF}$ = 1.205 V (typical)

Choose resistors R1 and R2 allows approximately 1.5 μA of current through the resistor divider. Lower value resistors can be used for improved noise performance, but consume more power. Avoid higher resistor values because leakage current into or out of FB across R1 / R2 creates an offset voltage that is proportional to $V_{OUT}$ divided by $V_{REF}$. The recommended design procedure is to choose R2 = 1 MΩ to set the divider current at 1.5 μA, and then calculate R1 using 方程式 3:

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R2 \tag{3}$$

图 8-2 depicts this configuration.

#### *8.2.1.2 External Capacitor Requirements*

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. As a rule of thumb, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors recommended in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

#### *8.2.1.3 Input and Output Capacitor Requirements*

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. An input capacitor is recommended if the source impedance is more than 0.5 Ω. A higher value capacitor may be necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved with the use of a large output capacitor. Use an output capacitor within the range specified in the *Recommended Operating Conditions* table for stability.

#### *8.2.1.4 Reverse Current*

Excessive reverse current can damage this device. Reverse current flows through the intrinsic body diode of the PMOS pass transistor instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device.

Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} \leqslant V_{IN}$ + 0.3 V. These conditions are:

- If the device has a large $C_{OUT}$ and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If reverse current flow is expected in the application, external protection is recommended to protect the device. Reverse current is not limited in the device, so external limiting is required if extended reverse voltage operation is anticipated. Limit reverse current to 5% or less of the rated output current of the device in the event this current cannot be avoided.


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图 8-3 shows one approach for protecting the device.

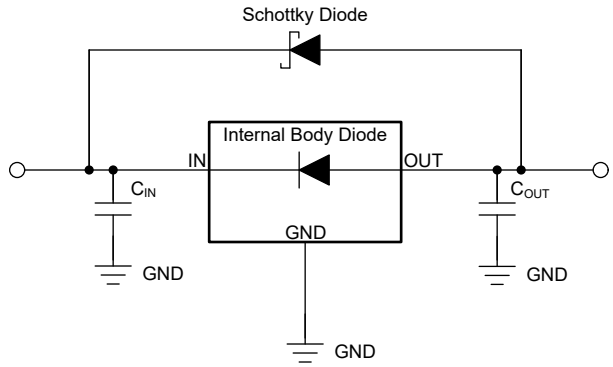


**图 8-3. Example Circuit for Reverse Current Protection Using a Schottky Diode**

#### *8.2.1.5 Feed-Forward Capacitor ($C_{FF}$)*

For the adjustable-voltage version device, a feed-forward capacitor ($C_{FF}$) can be connected from the OUT pin to the FB pin. $C_{FF}$ improves transient, noise, and PSRR performance, but is not required for regulator stability. Recommended $C_{FF}$ values are listed in the *Recommended Operating Conditions* table. A higher capacitance $C_{FF}$ can be used; however, the start-up time increases. For a detailed description of $C_{FF}$ tradeoffs, see the *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application note.

$C_{FF}$ and $R_1$ form a zero in the loop gain at frequency $f_Z$, while $C_{FF}$, $R_1$, and $R_2$ form a pole in the loop gain at frequency $f_P$. $C_{FF}$ zero and pole frequencies can be calculated from the following equations:

$$f_Z = 1 / (2 \times \pi \times C_{FF} \times R_1) \quad (4)$$

$$f_P = 1 / (2 \times \pi \times C_{FF} \times (R_1 \parallel R_2)) \quad (5)$$

$C_{FF} \geqslant 10$ pF is required for stability if the feedback divider current is less than 5 μA. 方程式 6 calculates the feedback divider current.

$$I_{FB_Divider} = V_{OUT} / (R_1 + R_2) \quad (6)$$

To avoid start-up time increases from $C_{FF}$, limit the product $C_{FF} \times R_1 < 50$ μs.

For an output voltage of 1.205 V with the FB pin tied to the OUT pin, no $C_{FF}$ is used.

#### *8.2.1.6 Power Dissipation ($P_D$)*

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must have few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. The following equation calculates power dissipation ($P_D$).

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (7)$$

**备注**

Power dissipation can be minimized, and therefore greater efficiency can be achieved, by correct selection of the system voltage rails. For the lowest power dissipation, use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area must contain an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature ($T_A$) for the device. According to the following equation, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air ($T_A$).

$$T_J = T_A + (R_{\theta JA} \times P_D) \tag{8}$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the *Thermal Information* table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance.

#### *8.2.1.7 Estimating Junction Temperature*

The JEDEC standard now recommends the use of psi ($\Psi$) thermal metrics to estimate the junction temperatures of the linear regulator when in-circuit on a typical PCB board application. These metrics are not thermal resistance parameters and instead offer a practical and relative way to estimate junction temperature. These psi metrics are determined to be significantly independent of the copper area available for heat-spreading. The *Thermal Information* table lists the primary thermal metrics, which are the junction-to-top characterization parameter ($\psi_{JT}$) and junction-to-board characterization parameter ($\psi_{JB}$). These parameters provide two methods for calculating the junction temperature ($T_J$), as described in the following equations. Use the junction-to-top characterization parameter ($\psi_{JT}$) with the temperature at the center-top of device package ($T_T$) to calculate the junction temperature. Use the junction-to-board characterization parameter ($\psi_{JB}$) with the PCB surface temperature 1 mm from the device package ($T_B$) to calculate the junction temperature.

$$T_J = T_T + \psi_{JT} \times P_D \tag{9}$$

where:

- $P_D$ is the dissipated power
- $T_T$ is the temperature at the center-top of the device package

$$T_J = T_B + \psi_{JB} \times P_D \tag{10}$$

where:

- $T_B$ is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

For detailed information on the thermal metrics and how to use them, see the *Semiconductor and IC Package Thermal Metrics* application note.


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### 8.2.2 Application Curves

at operating temperature $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 1.0 V or 2.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $C_{IN}$ = 1 µF, and $C_{OUT}$ = 1 µF (unless otherwise noted)

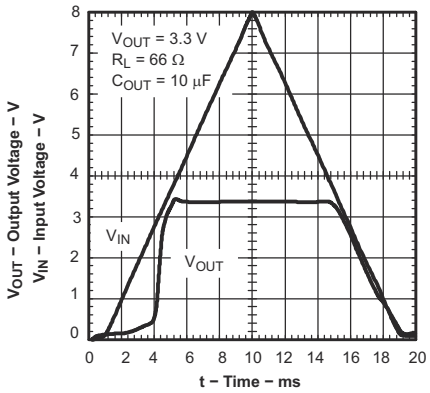


图 8-4. Power-Up and Power-Down for Legacy Chip

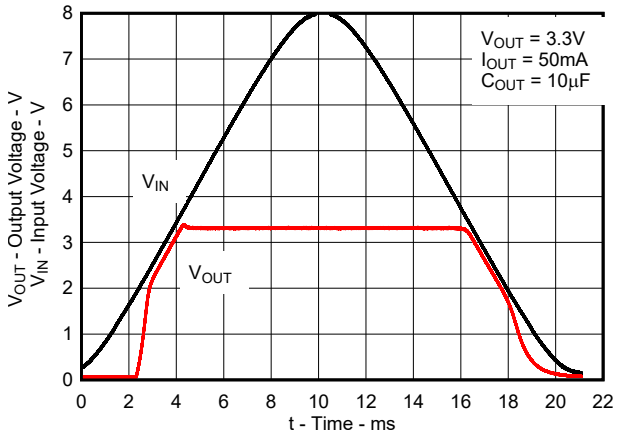


图 8-5. Power-Up and Power-Down for New Chip

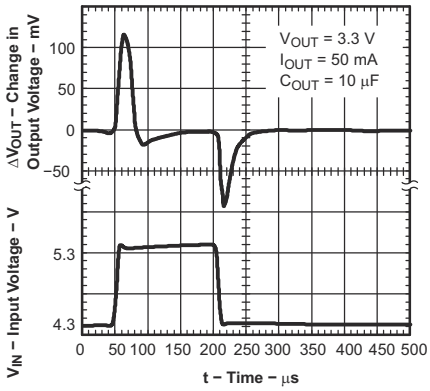


图 8-6. Line Transient Response for Legacy Chip

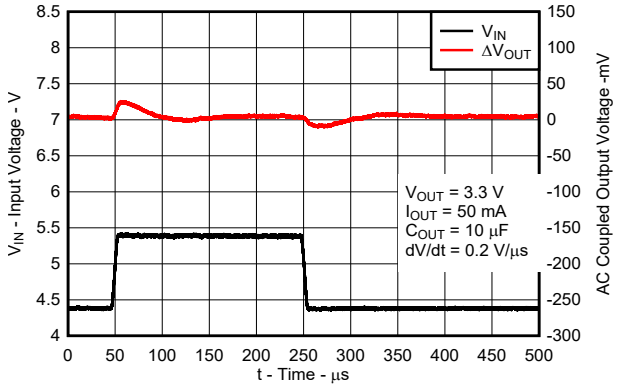


图 8-7. Line Transient Response for New Chip

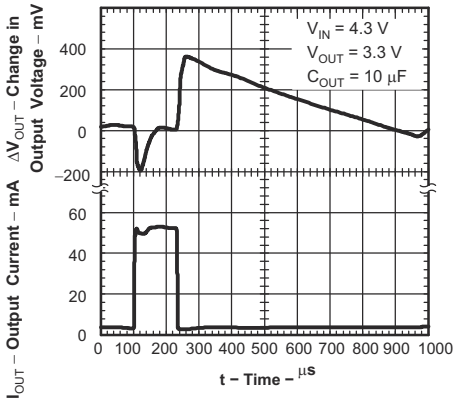


图 8-8. Load Transient Response for Legacy Chip

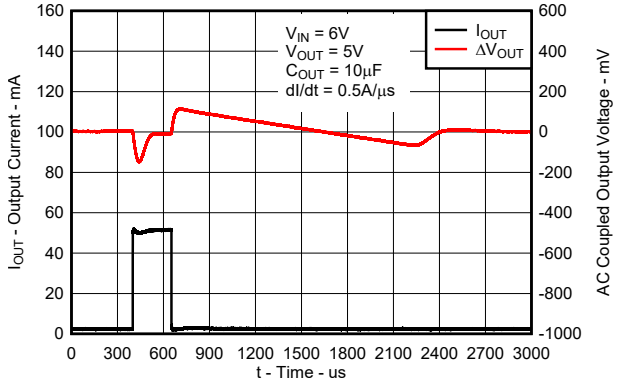


图 8-9. Load Transient Response for New Chip

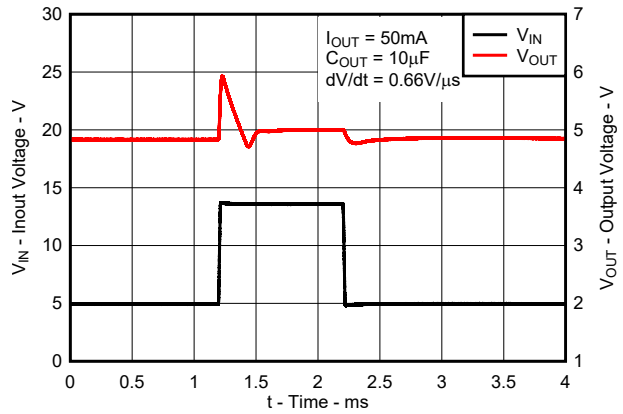


**图 8-10. Dropout Exit Transient Response for New Chip**

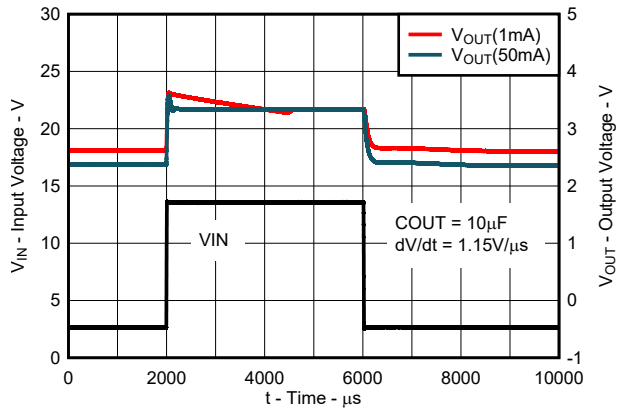


**图 8-11. Fast Line Transient Response for New Chip**

## 8.3 Best Design Practices

Place at least one 0.47-µF capacitor as close as possible to the OUT and GND terminals of the regulator.

Do not connect the output capacitor to the regulator using a long, thin trace.

Connect an input capacitor as close as possible to the IN and GND terminals of the regulator for best performance.

Do not exceed the absolute maximum ratings.

## 8.4 Power Supply Recommendations

The TPS715 is designed to operate from an input voltage supply range between 2.5 V and 24 V. The input voltage range provides adequate headroom in order for the device to have a regulated output. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

## 8.5 Layout

### 8.5.1 Layout Guidelines

For best overall performance, place all circuit components on the same side of the printed-circuit-board and as near as practical to the respective LDO pin connections. Place ground return connections for the input and output capacitors as close to the GND pin as possible, using wide, component-side, copper planes. Do not use vias and long traces to create LDO circuit connections to the input capacitor, output capacitor, or the resistor divider because this practice negatively affects system performance. This grounding and layout scheme minimizes inductive parasitics, and thereby reduces load-current transients, minimizes noise, and increases circuit stability. A ground reference plane is also recommended and is either embedded in the PCB itself or located on the bottom side of the PCB opposite the components. This reference plane serves to assure accuracy of the output voltage and shield the LDO from noise.

#### *8.5.1.1 Power Dissipation*

To ensure reliable operation, worst-case junction temperature must not exceed 125°C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, $P_D$, which must be less than or equal to $P_{D(max)}$.


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The maximum-power-dissipation limit is determined using 方程式 11:

$$P_{D(max)} = \frac{T_J max - T_A}{R_{\theta JA}} \tag{11}$$

where

- $T_J$max is the maximum allowable junction temperature
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package (see the *Thermal Information* table)
- $T_A$ is the ambient temperature

The regulator dissipation is calculated using 方程式 12:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \tag{12}$$

For a higher power package version of the TPS715, see the TPS715A.

### 8.5.2 Layout Example

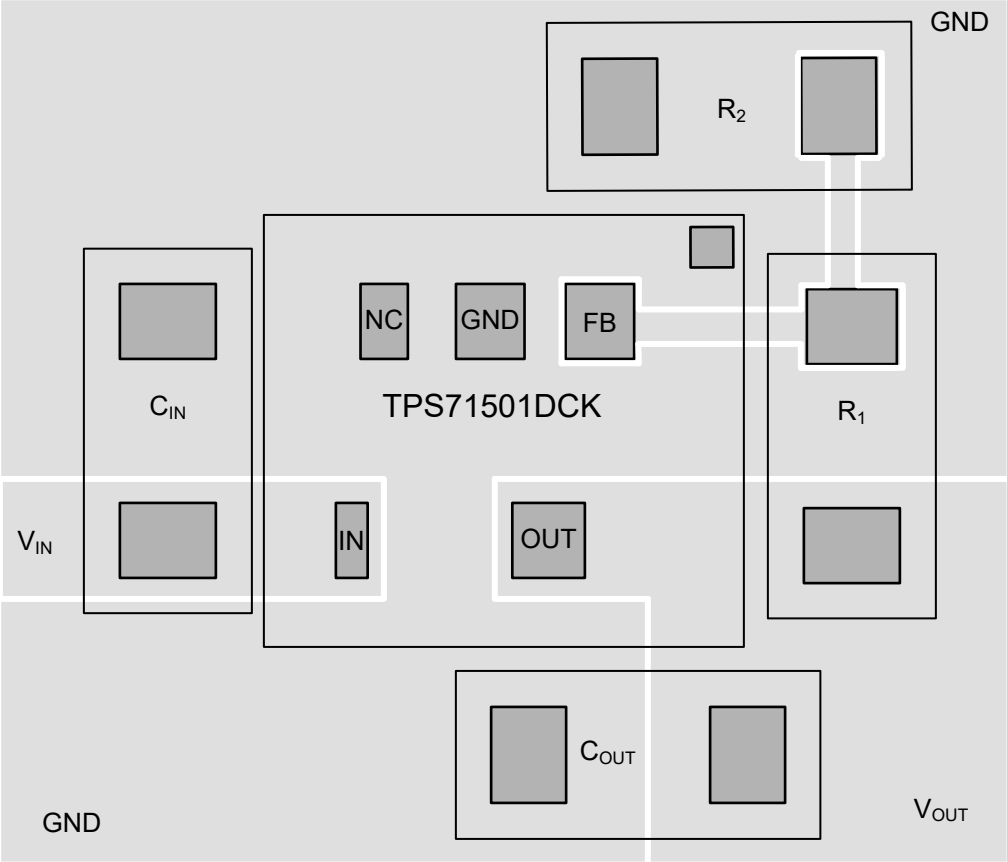


**图 8-12. Example Layout for the TPS71501DCK**

# 9 Device and Documentation Support

## 9.1 Device Support

### 9.1.1 Development Support

#### *9.1.1.1 Evaluation Module*

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS715. The TPS71533EVM evaluation module (and related user's guide) can be requested at the TI website through the product folders or purchased directly from the TI eStore.

#### *9.1.1.2 Spice Models*

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS715 is available through the product folders under *Tools & Software*.

### 9.1.2 Device Nomenclature

**表 9-1. Device Nomenclature**(1)

| PRODUCT | $V_{OUT}$ |
|---|---|
| TPS715**xxyyyz**<br>Legacy chip | **xx** is the nominal output voltage (for example, 28 = 2.8 V, 285 = 2.85 V, 01 = Adjustable).<br>**yyy** is the package designator.<br>**z** is the package quantity. |
| TPS715**xxyyyz M3**<br>New chip | **xx** is the nominal output voltage (for example, 28 = 2.8 V, 285 = 2.85 V, 01 = Adjustable).<br>**yyy** is the package designator.<br>**z** is the package quantity.<br>**M3** is a suffix designator for new chip redesigns on the latest TI process technology. |

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

## 9.2 Documentation Support

### 9.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *TPS715A 24-V High Input Voltage, Micropower, 80-mA LDO Voltage Regulator* data sheet
- Texas Instruments, *TPS71533EVM LDO Evaluation Module* user guide
- Texas Instruments, *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application note
- Texas Instruments, *Know Your Limits* application note

## 9.3 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

## 9.4 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

## 9.5 Trademarks

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## 9.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 9.7 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

# 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|---|---|---|---|---|---|---|---|---|---|---|---|
| TPS71501DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU \| NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | ARB | Samples |
| TPS71501DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ARB | Samples |
| TPS71501DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ARB | Samples |
| TPS71518DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | ARD | Samples |
| TPS71518DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | ARD | Samples |
| TPS71518DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ARD | Samples |
| TPS71519DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | BOX | Samples |
| TPS71523DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU \| NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | BNX | Samples |
| TPS71523DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | BNX | Samples |
| TPS71525DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQL | Samples |
| TPS71525DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQL | Samples |
| TPS71525DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQL | Samples |
| TPS71530DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQM | Samples |
| TPS71530DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQM | Samples |
| TPS71530DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQM | Samples |
| TPS71533DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQI | Samples |
| TPS71533DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQI | Samples |
| TPS71533DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AQI | Samples |
| TPS715345DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU \| NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | BNY | Samples |
| TPS715345DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | BNY | Samples |

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|---|---|---|---|---|---|---|---|---|---|---|---|
| TPS71550DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | T48 | Samples |
| TPS71550DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | T48 | Samples |
| TPS71550DCKRM3 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | T48 | Samples |

(1) The marketing status values are defined as follows:
**ACTIVE:** Product device recommended for new designs.
**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.
**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS715 :**

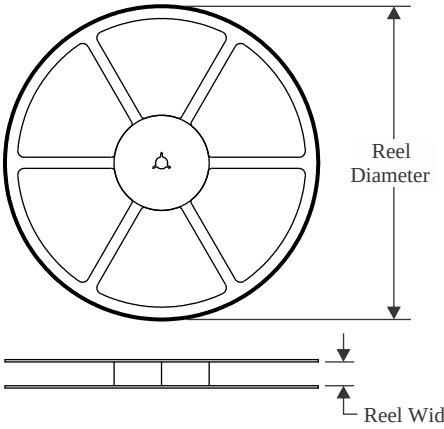
- Automotive : TPS715-Q1

NOTE: Qualified Version Definitions:

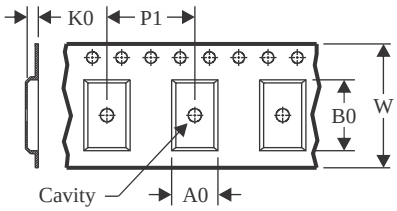
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

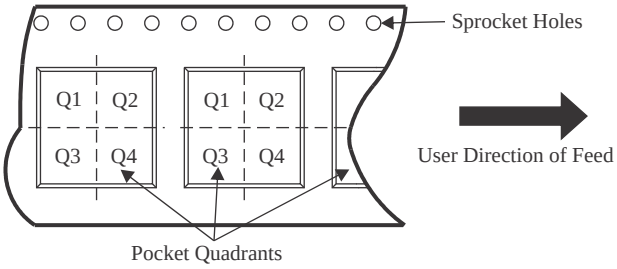



**TAPE DIMENSIONS**




| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

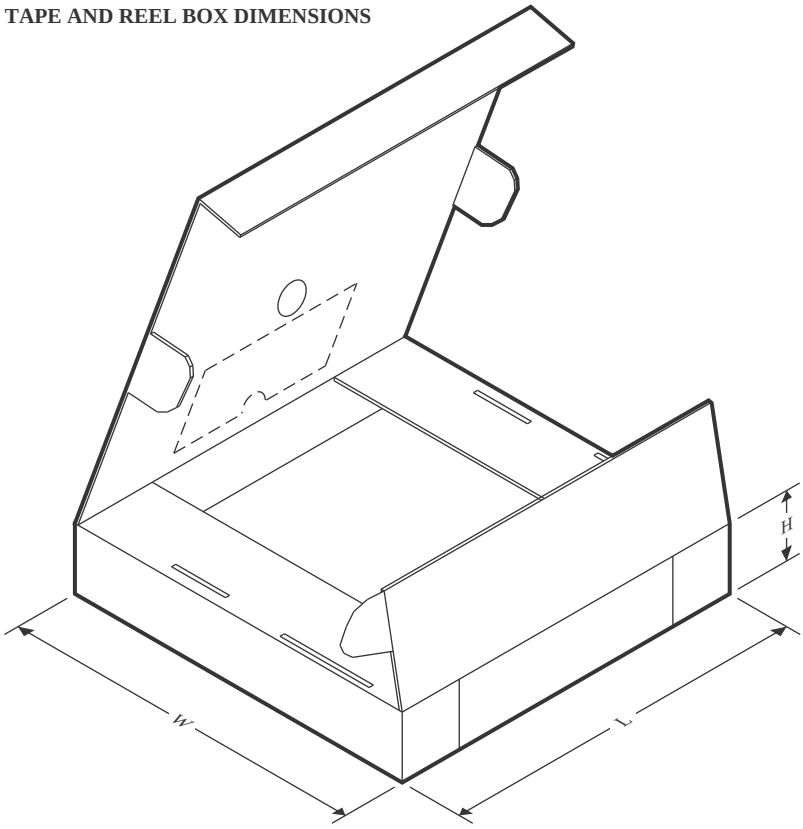



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| TPS71501DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71501DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71518DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 8.4 | 2.41 | 2.41 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71518DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71519DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 8.4 | 2.41 | 2.41 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71523DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71523DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71525DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71525DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71530DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71530DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71533DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71533DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS715345DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS715345DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| TPS71550DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |

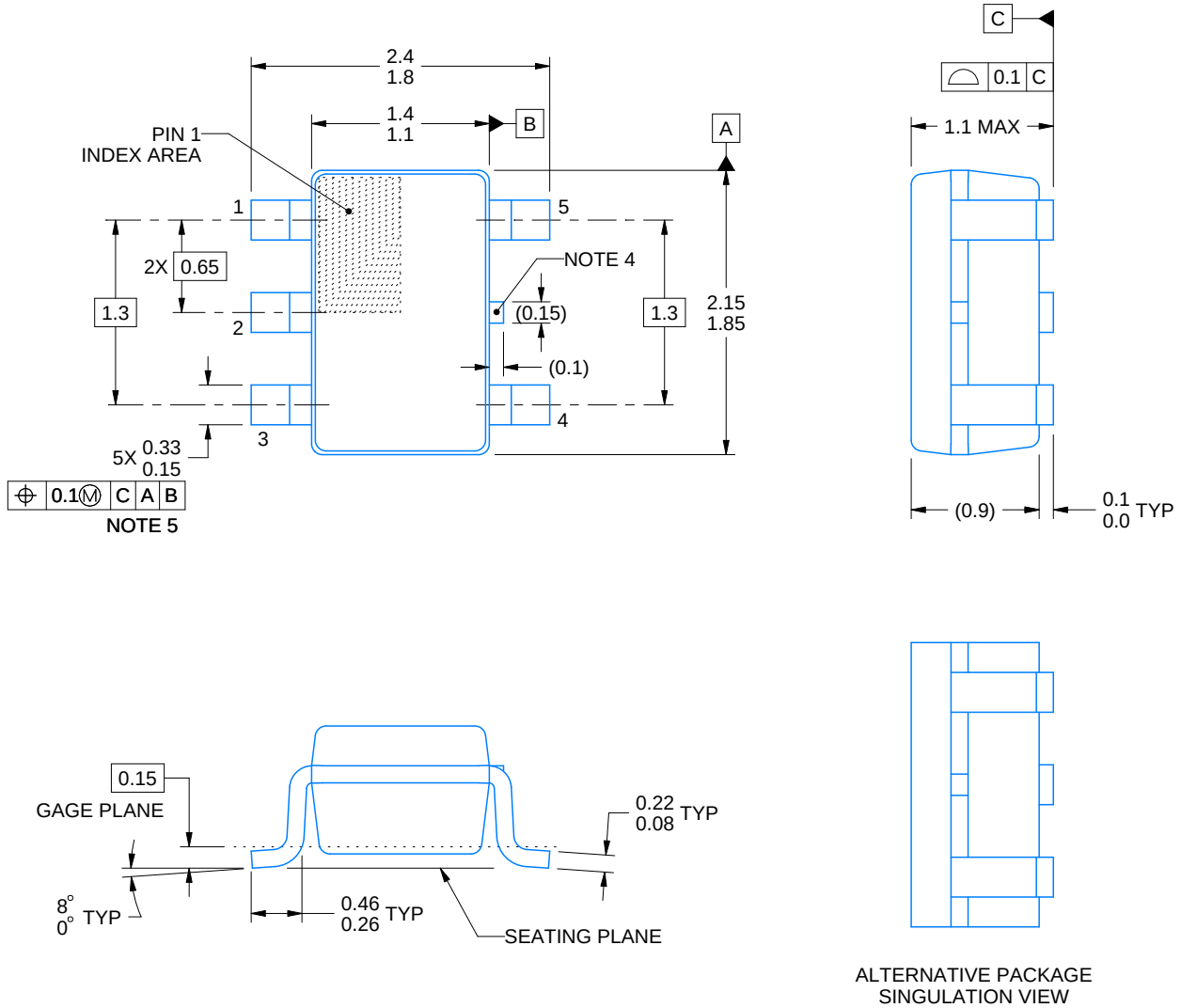
| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| TPS71550DCKRM3 | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |

TAPE AND REEL BOX DIMENSIONS




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| TPS71501DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71501DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71518DCKR | SC70 | DCK | 5 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS71518DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71519DCKR | SC70 | DCK | 5 | 3000 | 183.0 | 183.0 | 20.0 |
| TPS71523DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71523DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71525DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71525DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71530DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71530DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71533DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71533DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS715345DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS715345DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71550DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TPS71550DCKRM3 | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |

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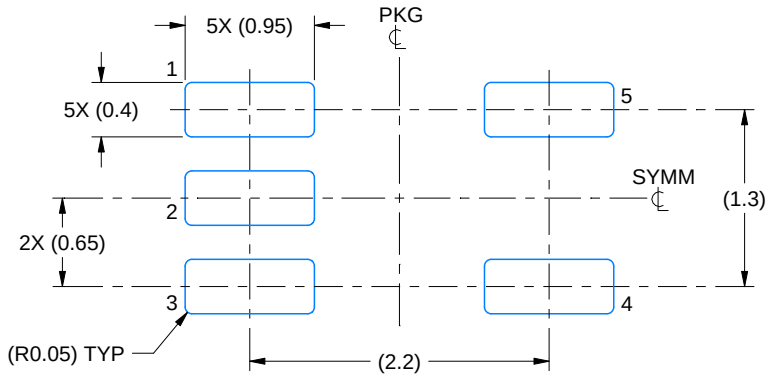
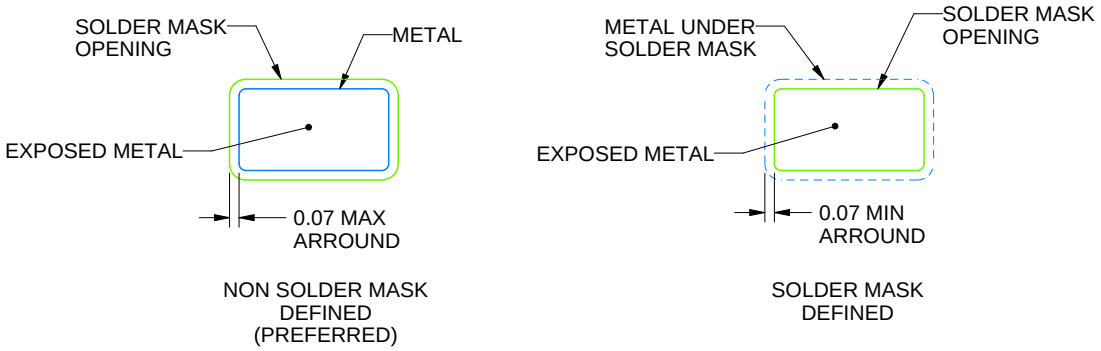
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X




SOLDER MASK DETAILS

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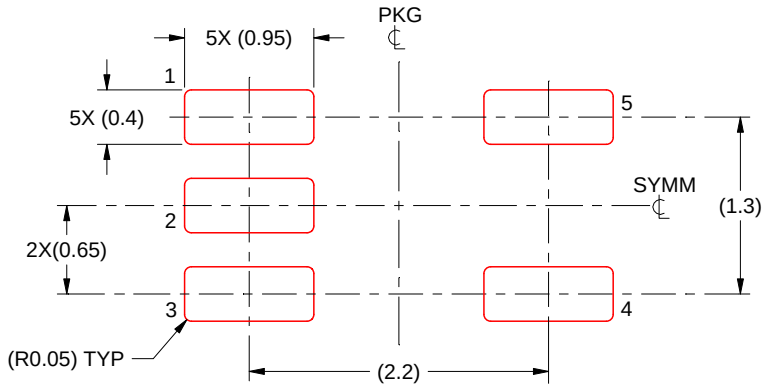
NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.




SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/E 06/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

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